

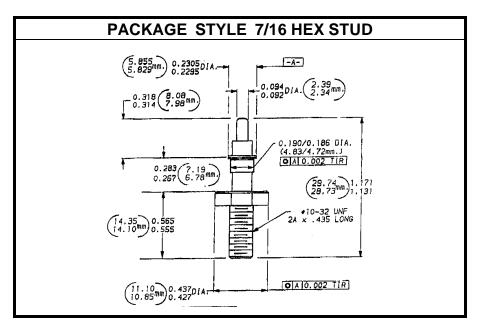
## SILICON STEP RECOVERY DIODE



The **DVB4376-99** is Designed for use in Moderate Power Multiplier Applications, Cathode Connected to Case.

## **MAXIMUM RATINGS**





## **CHARACTERISTICS** T<sub>C</sub> = 25 °C

SYMBOL	TEST CONDITIONS		MINIMUM	TYPICAL	MAXIMUM	UNITS
$V_{B}$	I <sub>R</sub> = 10 μA		85			٧
C <sub>t</sub>	$V_R = 0 V$	f = 1.0 MHz		12		рF
C <sub>t</sub>	V <sub>R</sub> = 6.0 V	f = 1.0 MHz	8.0		11.5	pF
T∟	MINORITY CARRIER LIFETIME				400	mS